

30V Dual P-Channel MOSFET



SOP-8

Pin Definition:

1. Source 2. Gate 1 3. Source 4. Gate 2

1. Source 1 8. Drain 1 2. Gate 1 7. Drain 1 3. Source 2 6. Drain 2 4. Gate 2 5. Drain 2

PRODUCT SUMMARY

V _{DS} (V)	$R_{DS(on)}(m\Omega)$	I _D (A)	
-30	25 @ V _{GS} = -10V	-7.1	
	41 @ V _{GS} = -4.5V	-5.5	

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

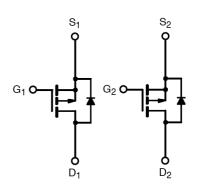
- Load Switches
- Notebook PCs
- Desktop PCs

Ordering Information

Part No.	Package	Packing
TSM4925DCS RLG	SOP-8	2.5Kpcs / 13" Reel

Note: "G" denotes for Halogen Free

Block Diagram



Dual P-Channel MOSFET

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V_{DS}	-30	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Drain Current		I _D	-7.1	А	
Pulsed Drain Current		I _{DM}	-40	А	
Continuous Source Current (Diode Co	onduction) ^{a,b}	I _S	-1.7	А	
Marine Deven Disable time	V_{DS} V_{GS} V_{GS} I_{D} I_{DM} $Conduction)^{a,b}$ I_{S} $Ta = 25^{\circ}C$ $Ta = 75^{\circ}C$ T_{J}	-	2.0	10/	
Maximum Power Dissipation	Ta = 75°C	P_{D}	1.3	W	
Operating Junction Temperature		TJ	+150	°C	
Operating Junction and Storage Temp	ge Temperature Range T _J , T _{STG} - 55 to +150		°C		

Thermal Performance

Parameter	Symbol	Limit	Unit			
Junction to Case Thermal Resistance	R⊖ _{JC}	30	°C/W			
Junction to Ambient Thermal Resistance (PCB mounted)	RO _{JA}	50	°C/W			

Notes:

- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on FR4 Board, $t \le 10$ sec.



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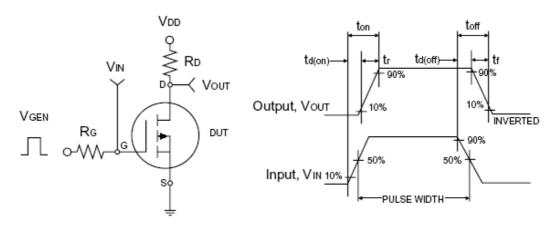
Pb RoHS

Electrical Specifications (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = -250uA$	BV _{DSS}	-30			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	$V_{GS(TH)}$	-1		-3	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -30V, V_{GS} = 0V$	I _{DSS}			-1.0	μΑ
On-State Drain Current ^a	$V_{DS} = -5V, V_{GS} = -10V$	I _{D(ON)}	-40			Α
Drain-Source On-State Resistance	$V_{GS} = -10V, I_D = -7.1A$			20	25	mΩ
Drain-Source On-State Resistance	$V_{GS} = -4.5V, I_{D} = -5.5A$	R _{DS(ON)}		33	41	
Forward Transconductance ^a	$V_{DS} = -10V, I_{D} = -7.1A$	g fs		24		S
Diode Forward Voltage	$I_S = -1.7A$, $V_{GS} = 0V$	V_{SD}		-0.8	-1.2	V
Dynamic ^b						
Total Gate Charge	$V_{DS} = -15V, I_{D} = -7.1A,$	Q_g		33	70	
Gate-Source Charge	$V_{DS} = -15V, I_D = -7.1A,$ $V_{GS} = -10V$	Q_gs		5.8		nC
Gate-Drain Charge	V _{GS} = -10 V	Q_gd		8.6		
Input Capacitance	\/ 45\/ \/ O\/	C_{iss}		1573	1900	
Output Capacitance	$V_{DS} = -15V, V_{GS} = 0V,$ $f = 1.0MHz$	C _{oss}		319		pF
Reverse Transfer Capacitance	I = 1.0IVIMZ	C_{rss}		211	295	
Switching ^c						
Turn-On Delay Time	V 45V D 450	t _{d(on)}		10	15	
Turn-On Rise Time	$V_{DD} = -15V, R_{L} = 15\Omega,$	t _r		15	25	~ C
Turn-Off Delay Time	$I_D = -1A$, $V_{GEN} = -10V$,	t _{d(off)}		110	170	nS
Turn-Off Fall Time	$R_G = 6\Omega$	t _f		70	110	

Notes:

- a. pulse test: PW \leq 300 μ S, duty cycle \leq 2%
- b. For DESIGN AID ONLY, not subject to production testing.
- b. Switching time is essentially independent of operating temperature.



Switching Test Circuit

Switchin Waveforms

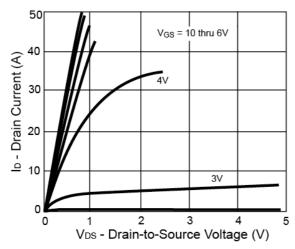


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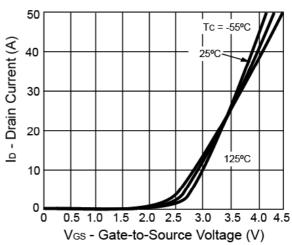


Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

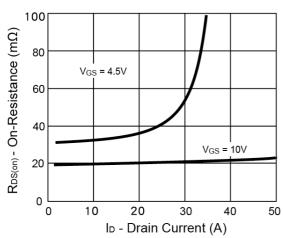
Output Characteristics



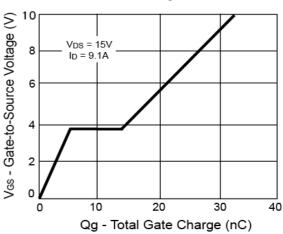
Transfer Characteristics



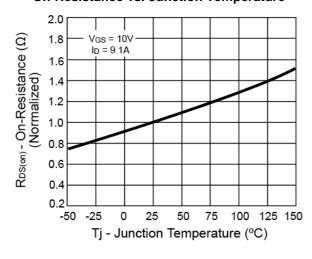
On-Resistance vs. Drain Current



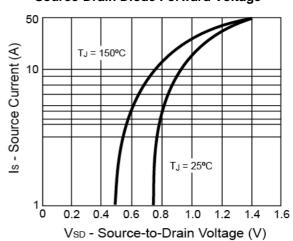
Gate Charge



On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage



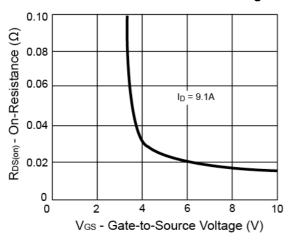


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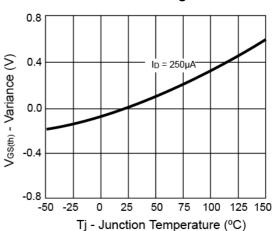


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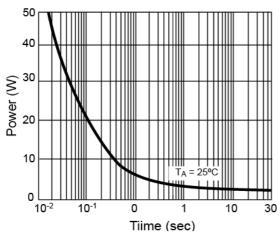
On-Resistance vs. Gate-Source Voltage



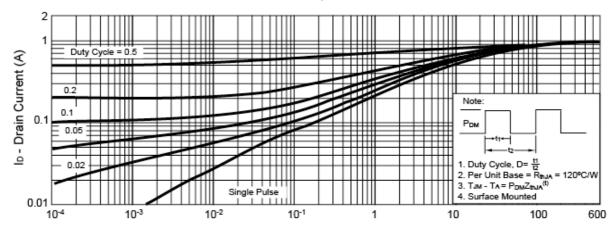
Threshold Voltage



Single Pulse Power



Normalized Thermal Transient Impedance, Junction-to-Ambient



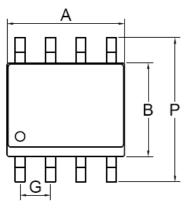
Square Wave Pulse Duration (sec)

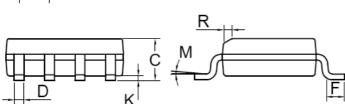


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SOP-8 Mechanical Drawing





SOP-8 DIMENSION					
DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX.	
Α	4.80	5.00	0.189	0.196	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.05	BSC	
K	0.10	0.25	0.004	0.009	
М	00	7°	00	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar R =Apr

S =May T =Jun U =Jul V =Aug W =Sep X =Oct Y =Nov Z =Dec

L = Lot Code



TSM4925D 30V Dual P-Channel MOSFET

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